

## Description

The IW4066B is a quad bilateral switch intended for the transmission or multiplexing of analog or digital signals.

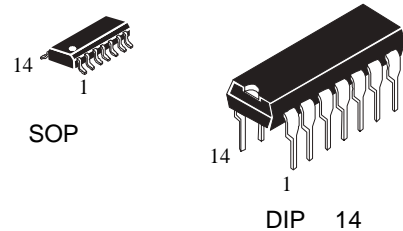
The IW4066B consists of four independent bilateral switches. A single control signal is required per switch.

Both the p and the n device in a given switch are biased on or off simultaneously by the control signal.(As show in Fig.1.)The well of the n-channel device on each switch is either tied to the input when the switch is on or to GND when the switch is off. This configuration eliminates the variation of the switch – transistor threshold voltage with input signal, and thus keeps the on-state resistance low over the full operating-signal range.

The advantages over single-channel switches include peak input- signal voltage swings equal to the full supply voltage, and more

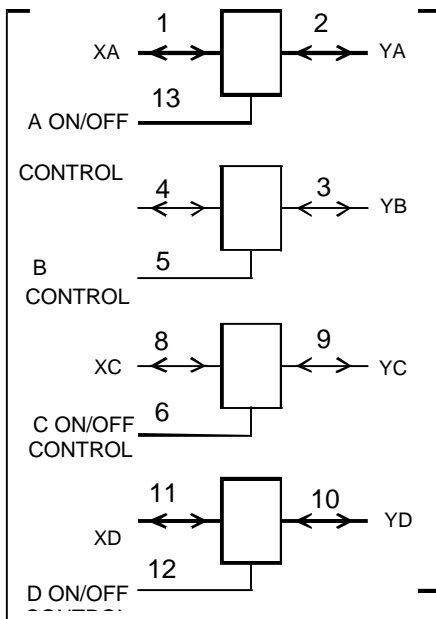
## Features


- Operating Voltage Range: 3.0 to 18 V
- Maximum input current of 1 at 18 V over full package-temperature range ;100 nA at 18 V and 25 C
- Noise margin (over full package temperature range):  
 1.0 V min @ 5.0 V supply  
 2.0 V min @ 10.0 V supply  
 2.5 V min @ 15.0 V supply



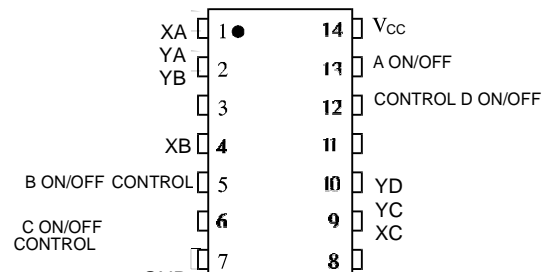
Package

## Logic Diagram



PIN 14 =  


## Pin Assignment



## Function Table

On/Off Control Input	State of Analog Switch
L	Off
H	On

## Absolute Maximum Ratings

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	DC Supply Voltage (Referenced to GND)	-0.5 to +20	V
V <sub>IN</sub>	DC Input Voltage (Referenced to GND)	-0.5 to V <sub>CC</sub> +0.5	V
V <sub>OUT</sub>	DC Output Voltage (Referenced to GND)	-0.5 to V <sub>CC</sub> +0.5	V
I <sub>IN</sub>	DC Input Current, per Pin	± 10	mA
P <sub>D</sub>	Power Dissipation in Still Air, Plastic DIP+	750 500	mW
P <sub>D</sub>	Power Dissipation per Output Transistor	100	mW
T <sub>stg</sub>	Storage Temperature	-65 to +150	°C
T <sub>L</sub>	Lead Temperature, 1 mm from Case for 10 Seconds (Plastic DIP or SOIC Package)	260	°C

Maximum Ratings are those values beyond which damage to the device may occur. Functional operation should be restricted to the Recommended Operating Conditions.

+ Derating - Plastic DIP: - 10mW/°C from 65° to 125°C

SOIC Package : - 7 mW/°C from 65° to

## Recommended Operating Conditions

Symbol	Parameter	Min	Max	Unit
V <sub>CC</sub>	DC Supply Voltage (Referenced to GND)	3.0	18	V
V <sub>IN</sub> , V <sub>OUT</sub>	DC Input Voltage, Output Voltage (Referenced to GND)	0	V <sub>CC</sub>	V
T <sub>A</sub>	Operating Temperature, All Package Types	-55	+125	°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V<sub>IN</sub> and V<sub>OUT</sub> should be constrained to the range GND (V<sub>IN</sub> or V<sub>OUT</sub>) V<sub>CC</sub>.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V<sub>CC</sub>).

**DC Electrical Characteristics**

(Voltages Referenced to GND)

Symbol	Parameter	Test Conditions	V <sub>CC</sub> V	Guaranteed Limit			Unit
				≥ -55°C	25 °C	≤ 125 °C	
V <sub>IH</sub>	Minimum High-Level Voltage ON/Off Control Inputs	R <sub>ON</sub> = Per Spec	5.0 10 15	3.5(Min) 7(Min) 11(Min)			V
V <sub>IL</sub>	Minimum Low-Level Voltage ON/Off Control Inputs	R <sub>ON</sub> = Per Spec	5.0 10 15	1 2 2	1 2 2	1 2 2	V
I <sub>IN</sub>	Maximum Input Leakage Current, ON/OFF Control Inputs	V <sub>IN</sub> = V <sub>CC</sub> or GND	18	± 0.1	± 0.1	± 1.0	uA
I <sub>CC</sub> Quiescent	Maximum Supply Current	V <sub>IN</sub> = V <sub>CC</sub> or GND	5.0 10 15 20	0.25 0.5 1 5	0.25 0.5 1 5	7.5 15 30 150	uA
R <sub>ON</sub>	Maximum "ON" Resistance	V <sub>C</sub> = V <sub>CC</sub> R <sub>L</sub> = 10 kΩ returned to $\frac{V_{CC} - GND}{2}$	5.0 10 15	800 310 200	1050 400 240	1300 550 320	Ω
R <sub>ON</sub>	Maximum Difference in "ON" Resistance Between Any Two Channels in the Same Package	V <sub>IS</sub> = GND to V <sub>CC</sub> V <sub>C</sub> = V <sub>CC</sub> R <sub>L</sub> = 10 kΩ	5.0 10 15	- - -	15 10 5	- - -	Ω
I <sub>OFF</sub>	Maximum Off-Channel Leakage Current, Any One	V <sub>C</sub> = 0 V V <sub>IS</sub> = 18 V, V <sub>OS</sub> = 0 V	18	± 0.1	± 0.1	± 1.0	uA
I <sub>ON</sub>	Maximum On-Channel Leakage Current, Any One Channel	V <sub>C</sub> = 0 V V <sub>IS</sub> = 18 V, V <sub>OS</sub> = 0 V V <sub>IS</sub> = 0 V, V <sub>OS</sub> = 18V	18	± 0.1	± 0.1	± 1.0	uA

## AC Electrical Characteristics

 (C<sub>L</sub>=50pF, R<sub>L</sub>=200 kΩ, Input t<sub>r</sub>=t<sub>f</sub>=20 ns)

Symbol	Parameter	V	ns)			Unit
			≥-55°C	25°C	≤ 125°C	
t <sub>PLH</sub> , t <sub>PHL</sub>	Maximum Propagation Delay Analog Input to Analog Output (Figure 2)	5.0 10 15	40 20 15	40 20 15	80 40 30	ns
t <sub>PLZ</sub> t <sub>PH</sub> t <sub>P</sub> t <sub>PZH</sub>	Maximum Propagation Delay, ON/OFF Control to Analog Output (Figure 3)	5.0 10 15	70 40 30	70 40 30	140 80 60	ns
C	Maximum Capacitance ON/OFF Control Input Control Input = GND Analog I/O Feedthrough	-		15 7.5 0.6		pF

## Additional Application Characteristics

(Voltages Referenced to GND Unless Noted)

Symbol	Parameter	Test Conditions	V <sub>CC</sub> V	Limit 25°C	Unit
THD	Total Harmonic Distortion	V <sub>C</sub> = V <sub>CC</sub> , GND = -5 V R <sub>L</sub> = 10 kΩ, f <sub>IS</sub> =1 kHz sine wave	5	0.4	%
BW	Maximum On-Channel Bandwidth or Minimum Frequency Response	V <sub>C</sub> = V <sub>CC</sub> , GND = -5 V R <sub>L</sub> = 1	5	40	MHz
BW	Maximum On-Channel Bandwidth or Minimum Frequency Response	V <sub>C</sub> = GND, V <sub>IS</sub> = 5 V R <sub>L</sub> = 1	10	1	MHz
BW	Maximum On-Channel Bandwidth or Minimum Frequency Response	V <sub>C</sub> (A) = V <sub>CC</sub> = 5 V V <sub>C</sub> (B) = GND = -5 V V <sub>IS</sub> (A) = 5 V P-P, 50 W source R <sub>L</sub> = 1 kΩ	5	8	MHz
-	Cross talk (Control Input to Signal Output)	V <sub>C</sub> = 10 V t <sub>r</sub> , t <sub>f</sub> = 20 ns R <sub>L</sub> = 10 kΩ	10	50	mV
-	Maximum Control Input Repetition Rate	V <sub>IS</sub> = V <sub>CC</sub> , R <sub>L</sub> = 1 kΩ C <sub>L</sub> = 50 pF V <sub>C</sub> = 10 V (square wave centered on 5 V) t <sub>r</sub> , t <sub>f</sub> = 20 ns, V <sub>OS</sub> = 1/2 V <sub>OS</sub> 1 kHz	5 10 15	6 9 9.5	MHz

\* Guaranteed limits not tested. Determined by design and verified by qualification.

V <sub>CC</sub> (V)	V <sub>IS</sub> (V)	Switch Input			Switch Output, V <sub>OS</sub> (V)	
		I <sub>IS</sub> (mA)			Min	Max
		-55 °C	+25 °C	+125 °C		
5	0	0.64	0.51	0.36	-	0.4
5	5	-0.64	-0.51	-0.36	4.6	-
10	0	1.6	1.3	0.9	-	0.5
10	10	-1.6	-1.3	-0.9	9.5	-
15	0	4.2	3.4	2.4	-	1.5
15	15	-4.2	-3.4	-2.4	13.5	-

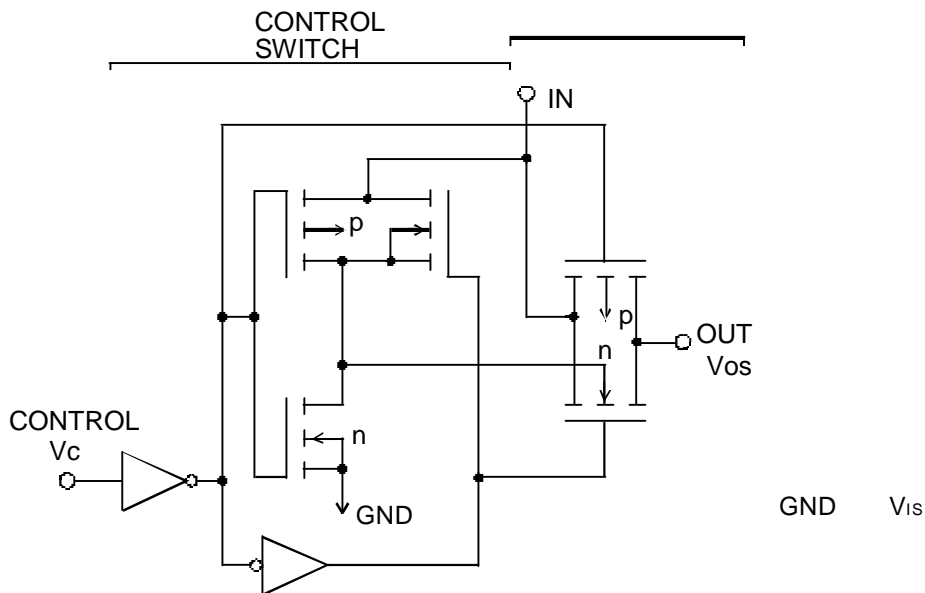


Figure 1. Schematic diagram of 1 of 4 identical switches and its associated control circuitry.

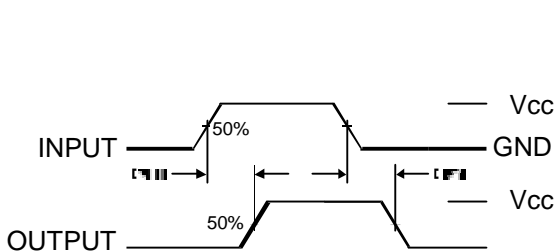


Figure 2. Switching Waveforms

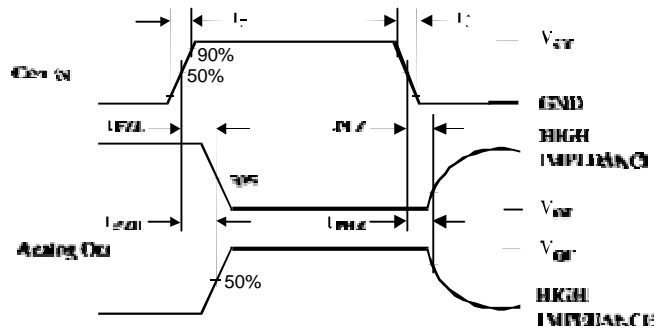
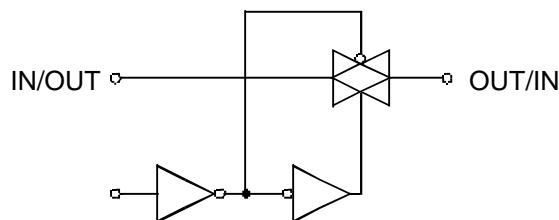


Figure 3. Switching Waveforms

## Expanded Logic Diagram (1/4 of the Device)



Control	Switch
GND = L	OFF
VCC = H	ON

Address : 北京市海淀区永定路 88 号长银大厦 6A06--6A07

Rm 6A07, Changyin Office Building ,No.88, Yong Ding Road, Hai Dian District ,Beijing

Postalcode:100039

Tel: 86-010-58895780 / 81 / 82 / 83 / 84 Fax : 010-58895793

Http://www.estek.com.cn

Email:sales@estek.com.cn

REV No:01-060835